



# Exercise: Simulating a Diode

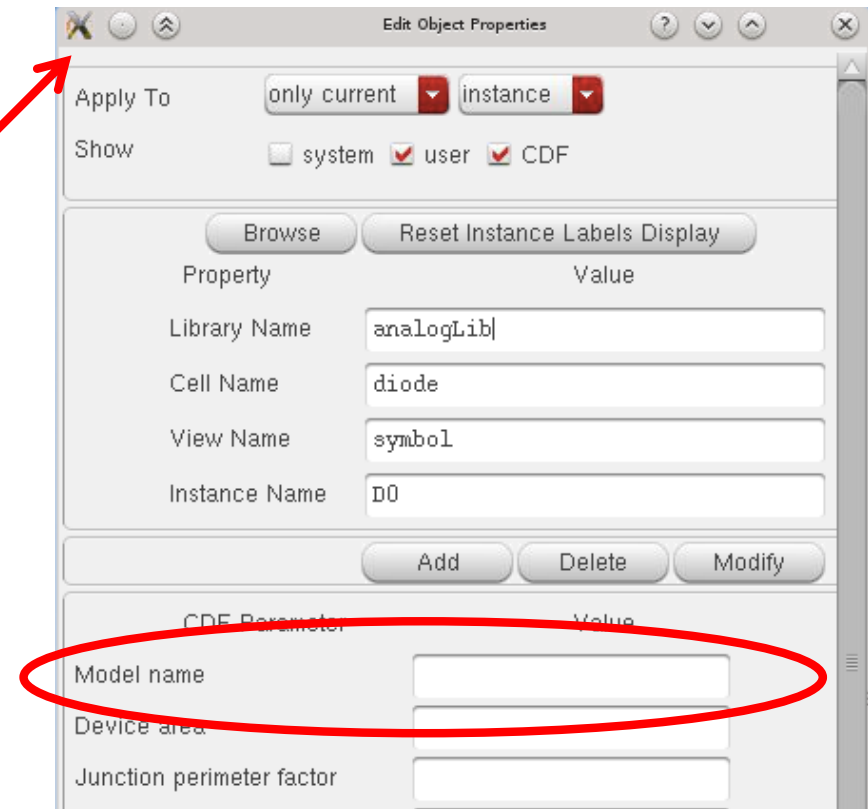
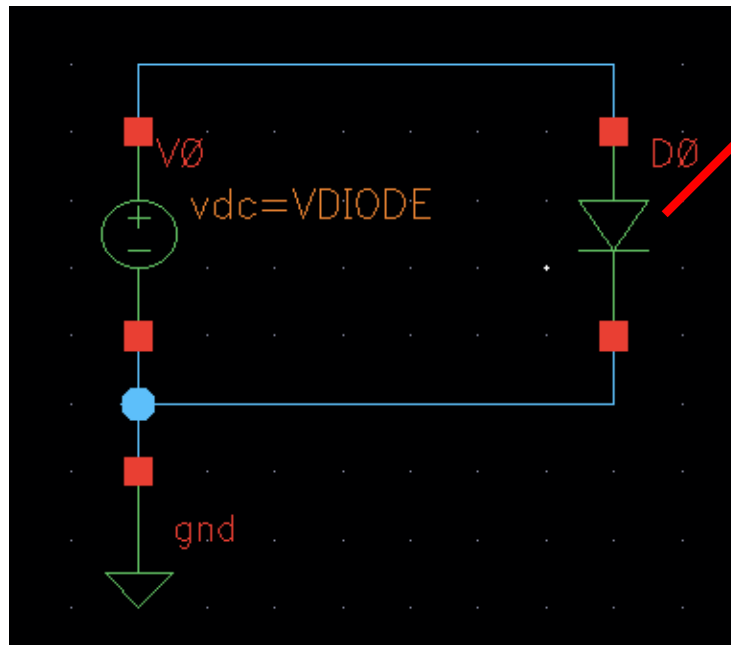
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# 1. Defining a Model

- Create the following schematic.
  - The diode is taken from `analogLib`
  - Note that NO model is associated to this 'generic' diode





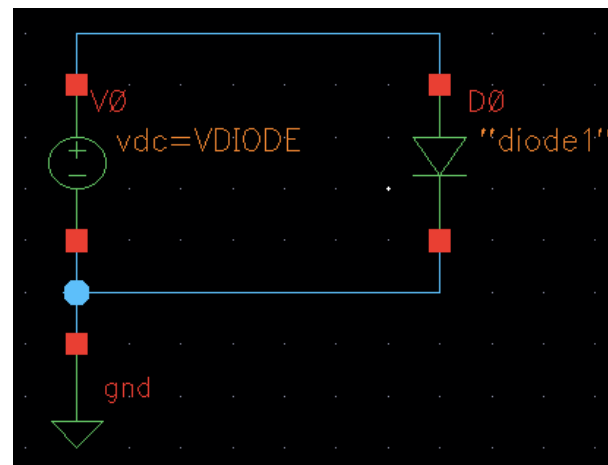
# Trying a DC simulation

- Simulate (DC!) the diode current for  $V_{DIODE} = 0 \dots 1V$ 
  - An error occurs:

'No model given'

```
Error found by spectre during hierarchy flattening.
ERROR (CMI-2119): D0: Instance (of type diode) requires the use of a model.
```

- Now assign a model with name 'diode1' to the diode:



- Run the simulation again:

'model given, but not defined / found'

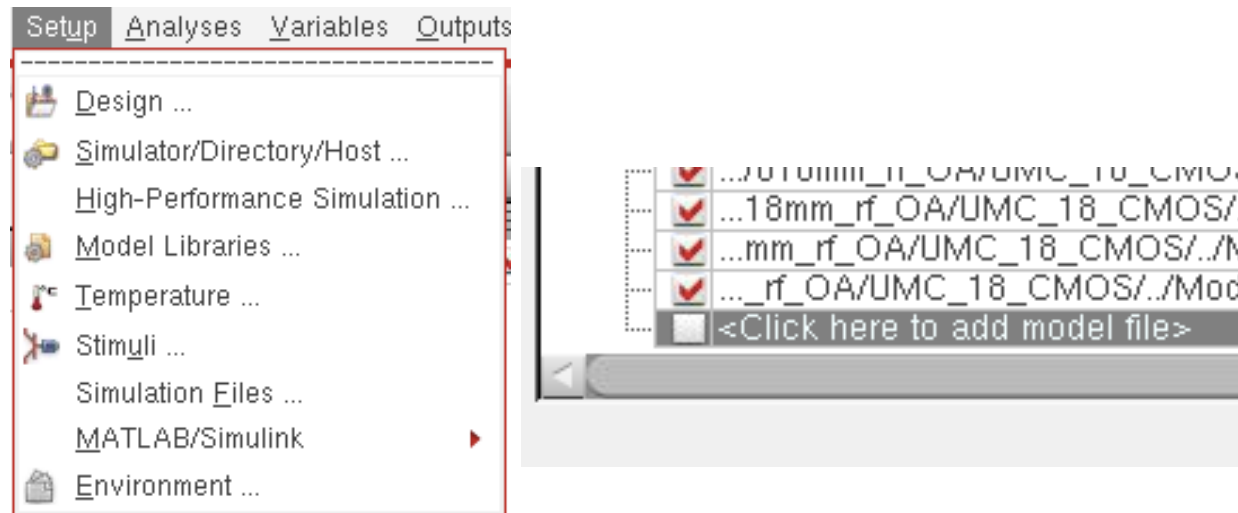
```
Error found by spectre during circuit read-in.
ERROR (SFE-23): "input.scs" 36: The instance `D0' is referencing an undefined model
```



# Defining a Model

- Create a text file `MyDiode.lib` with the following model definition:
 

```
.MODEL diode1 d IS=1e-08 RS=1 CJO=1e-11 VJ=0.7 M=0.5
```
- The simulator needs to know about this file:
  - In `Setup->Model Libraries...`, add your file `MyDiode.lib`.

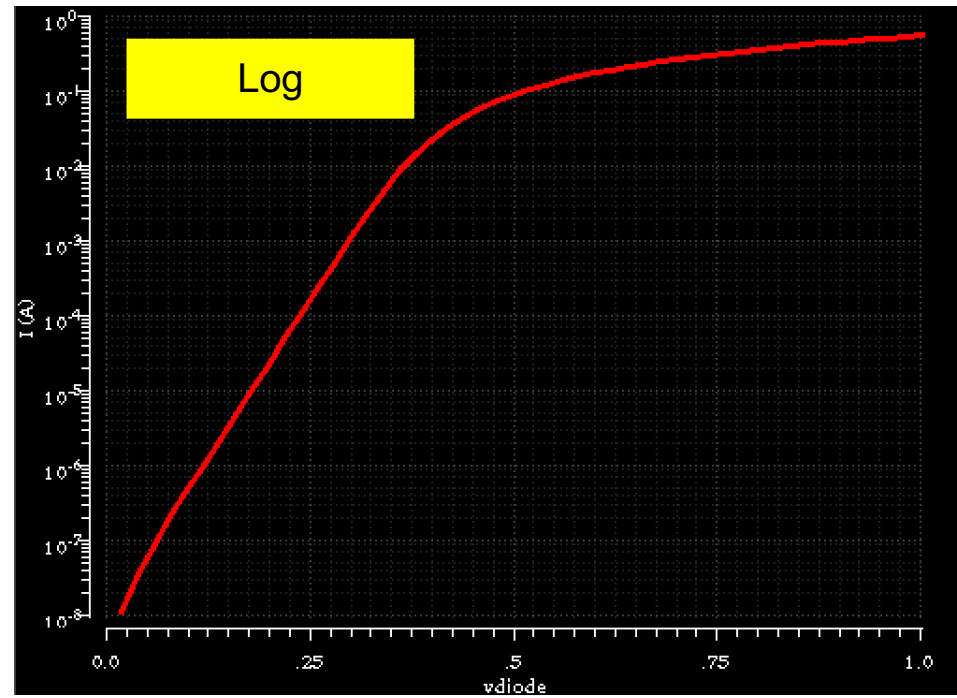
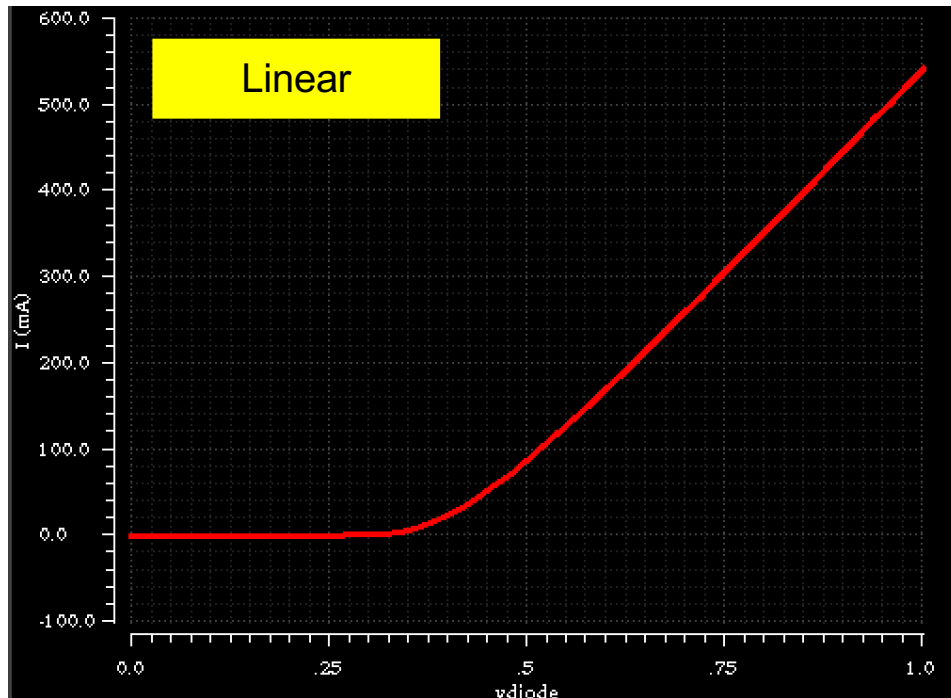


- Run the simulation again.
- Does the current increase exponentially? Try a log current scale! Sweep only to 0.4V! Why does  $I(U)$  become linear?



# Solution 1

- Sweeping to 1 V with this diode gives currents of several 100mA!

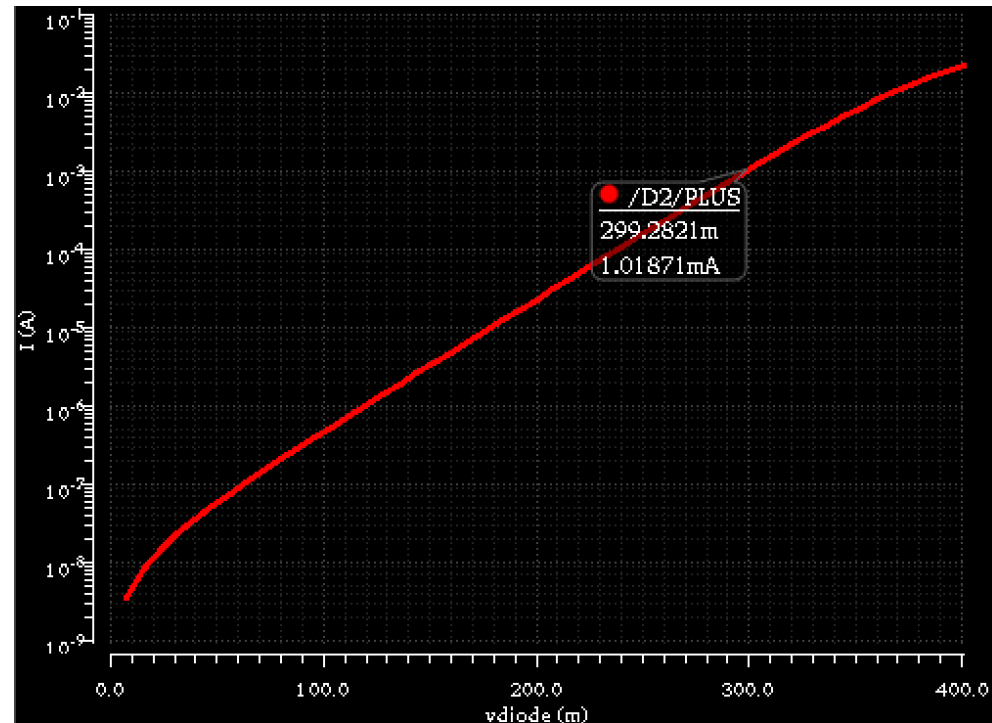


- In Log scale we can see, that the expected exponential behaviour stops at  $\sim 0.3V$  at some 10mA
- The reason is the series resistor  $R=1\Omega$  which generates a voltage drop of 10mV for 10mA..



# Solution 1

- For 0..400mV:



- For 300mV, the resistor makes nearly no effect.
- The expected current at 300mV for an ideal diode is  $I(0.3V) = IS (e^{300/25.86} - 1) = 1.09 \text{ mA}$ , as simulated



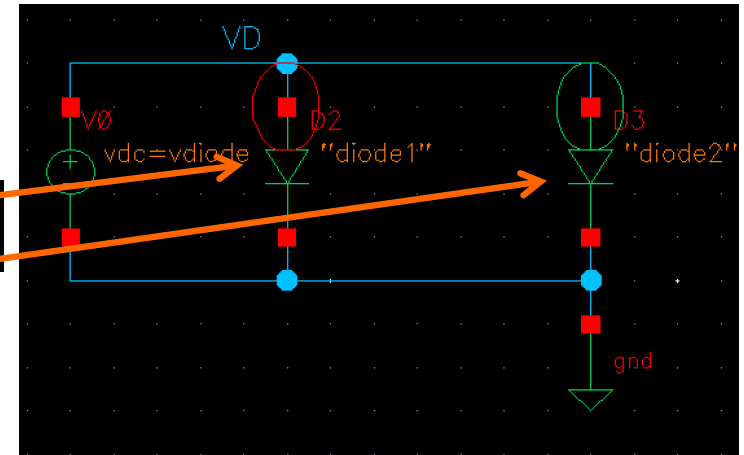
## 2. Different Models

- Instantiate a second diode with another model 'diode2'
- Add model 'diode2' to your `MyDiode.lib`. Change for instance `IS` to `2e-8`.
- Simulate and compare the two diode currents (best in log scale)
  
- **ATTENTION / NOTE:**
  - The simulator tries to be efficient and caches the models. If you just change `MyDiode.lib`, the change is not seen. There are (at least) 2 tricks to make sure the new model is used:
    - every time you change the model, use a *different model name* (and update the model name in the schematic)
    - Save `MyDiode.lib` under a *different file name* and include that new file in the model directory dialogue.

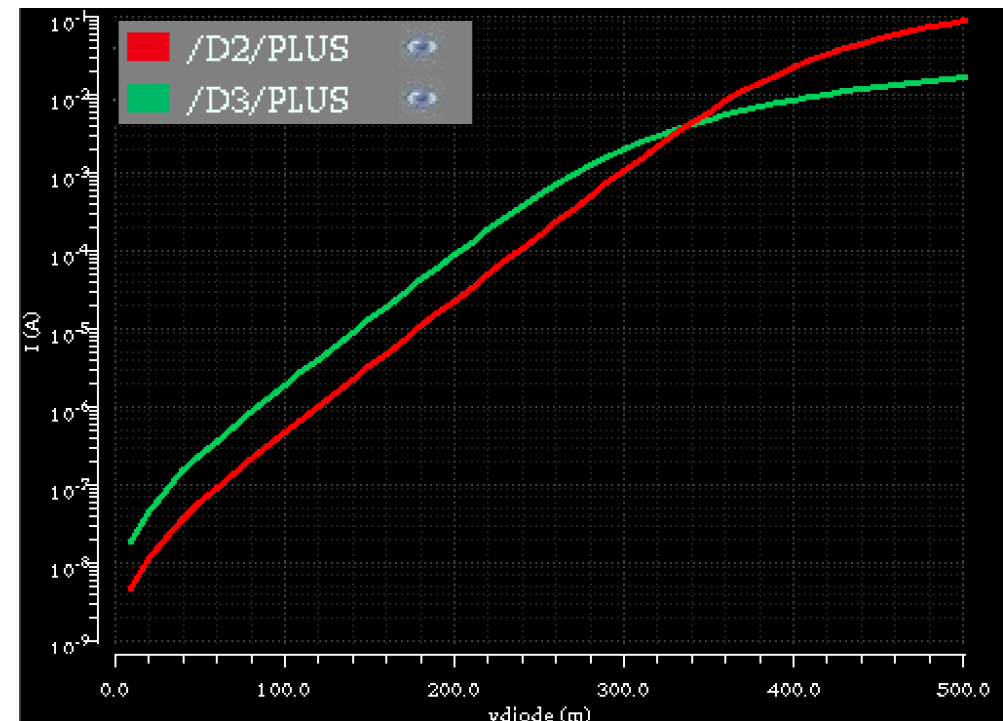


# Solution 2

```
.MODEL diode1 d IS=1e-8 RS=1 CJ0=1e-11 VJ=0.7 M=0.5
.MODEL diode2 d IS=4e-8 RS=10 CJ0=1e-11 VJ=0.7 M=0.5
```



- D3 has more current at same voltage
- Large series resistor of D3 kicks in earlier

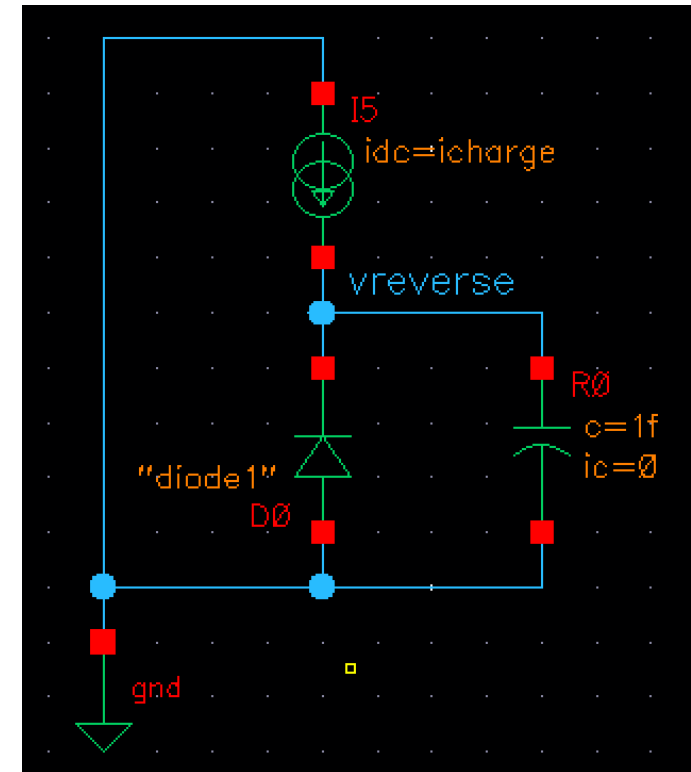






## 3. Capacitance

- To see the effect of the diode capacitance, you can charge it with a constant current *icharge*.
  - Make sure the polarity is such that the diode is in reverse bias
  - You can define the start voltage with a very small (1 fF) capacitor in parallel to the diode with an initial condition.
  
- Find a good value for *icharge* for your transient simulation
- Observe how the diode voltage increases with time. From the slope (calculator tool!), determine the capacitance
- Observe how the capacitance varies with voltage (time)
- Compare to what you expect from the model



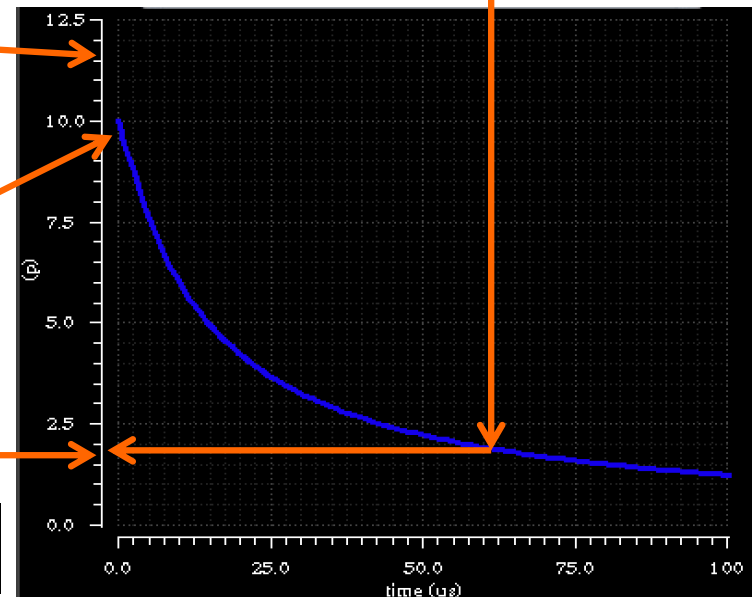
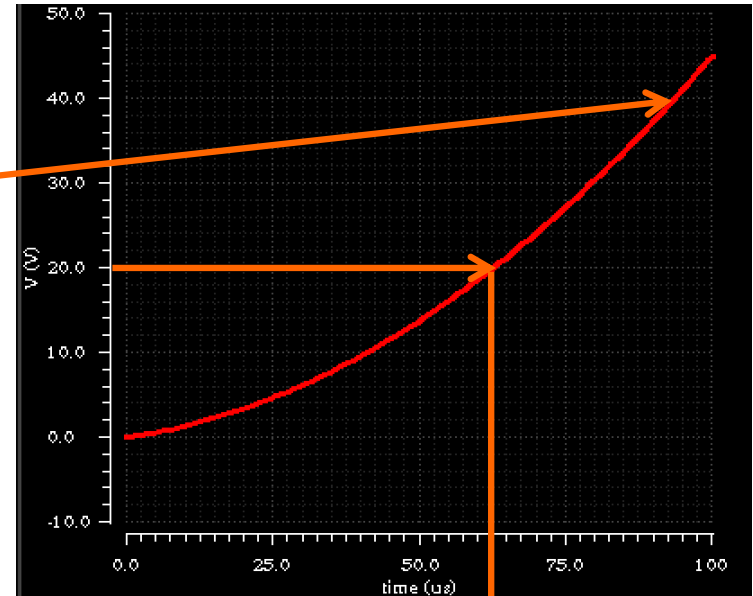


# Solution 3

- Charging with 1uA yields:
- The charging becomes *faster* for high voltages because capacitance *decreases*.
- Because  $dU/dt = I/C$ , Capacitance is  $C = I/(dU/dt) = 1\mu A/\text{slope}$ :

- Using  $C = C_{J0} \cdot \left(1 - \frac{U}{V_J}\right)^{-M}$  we expect

- At  $U=0$ :  $C = C_{J0} = 10\text{pF}$
- At  $-20\text{V}$ :  $C = 10\text{p} (1+20/0.7)^{-0.5} = 1.84\text{pF}$

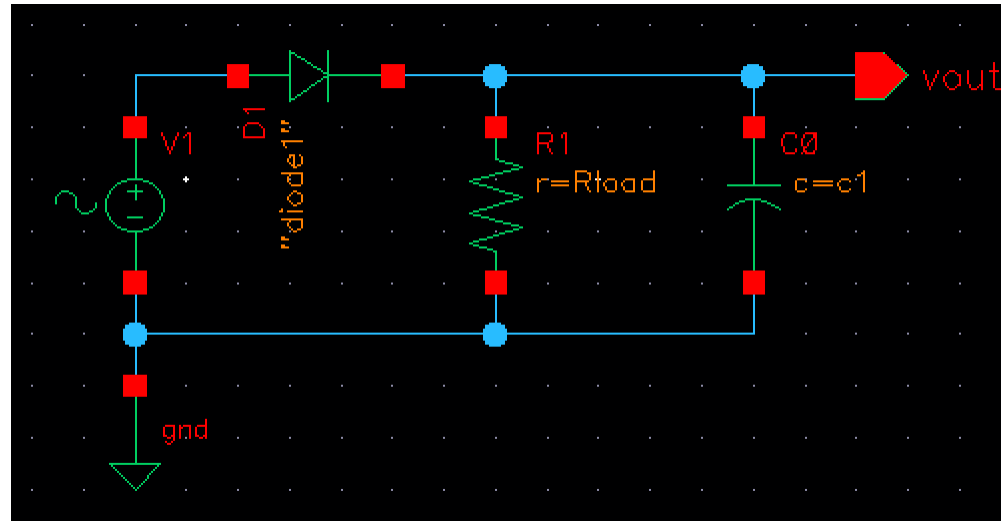


```
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.MODEL diode2 d IS=4e-8 RS=10 CJ0=1e-11 VJ=0.7 M=0.5
```



## 4: A Simple Rectifier

- Alternating voltages can be converted to 'dc' with a 'rectifier':

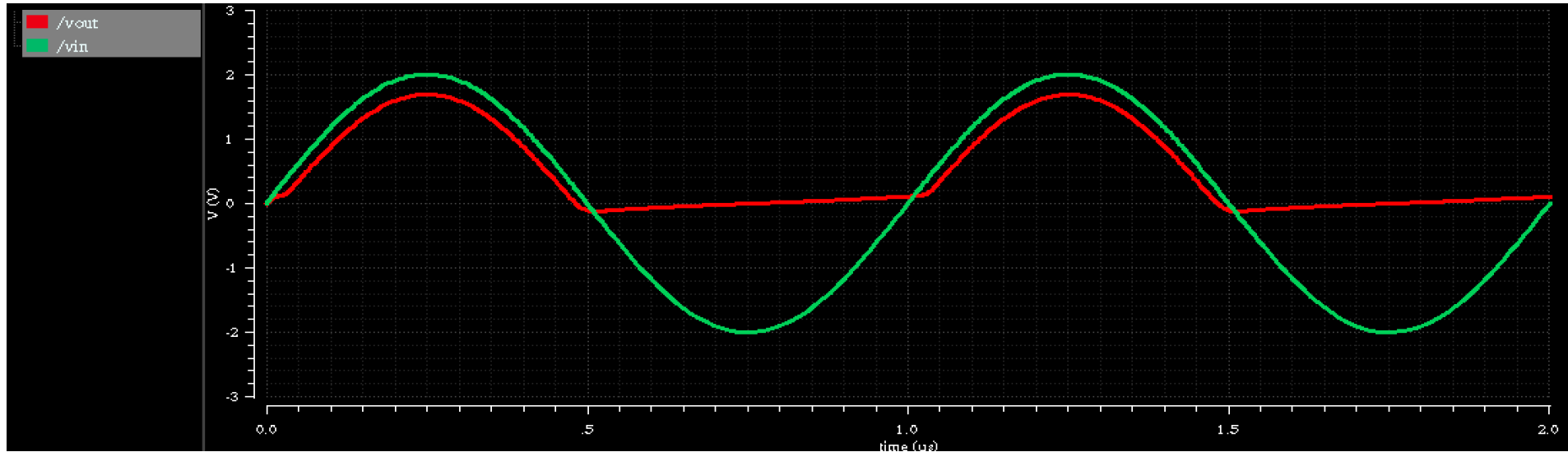


- Make a transient simulation (50 Hz, 10 V,  $R_{load}=1k\Omega$ ,  $C1=0$ )
  - Compare  $v_{in}$  and  $v_{out}$ . Observe the small difference in voltage. Where does it come from? How does that change with  $R_{load}$ ?
  - Now set  $C1$  to 1  $\mu\text{F}$ . Observe how  $v_{out}$  stays positive even in the negative phases of  $v_{in}$ . How does this work?
  - What are the effects of changing  $R_{load}$  and changing  $C1$ ?
  - Which  $C$  is needed to keep  $V_{out} > 8\text{V}$  for  $R_{load}=1k\Omega$ ? Calculate!

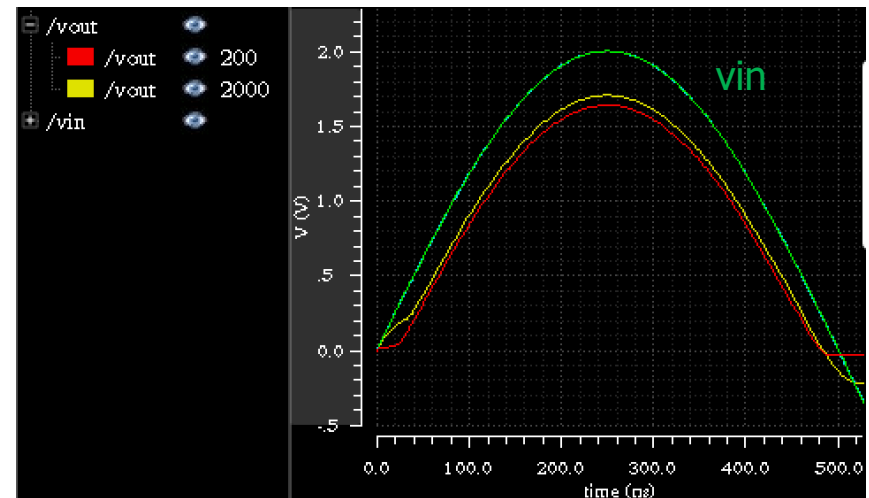


# Solution 4 (with different component values...)

- Using a 2V input at 1 MHz and  $R=1k$ , we get



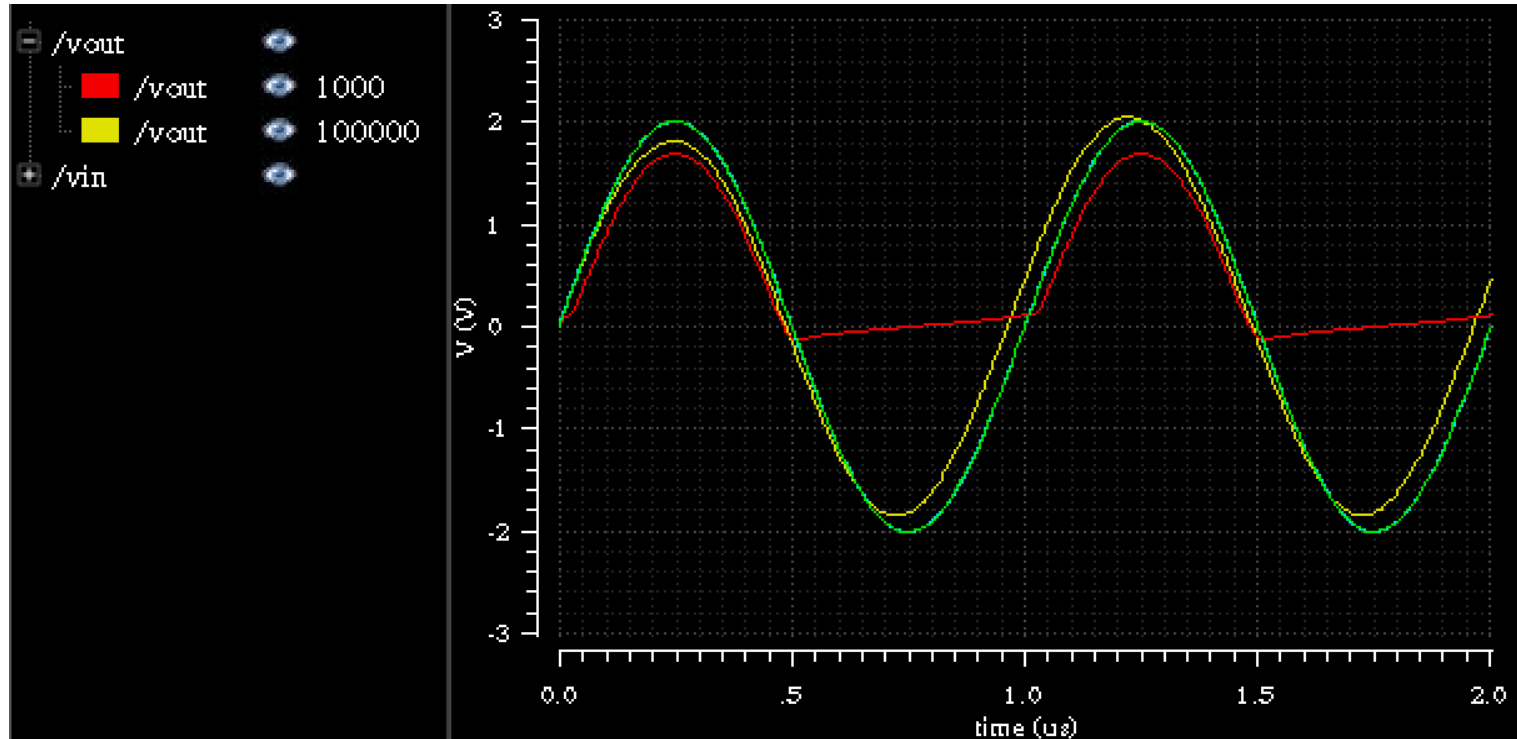
- The voltage difference is the forward diode voltage at the current the diode delivers. It is a bit more at high amplitudes (because current is higher)
- It is more for smaller  $R$ :





# Solution 4:

- Remark: for very high  $R$ , we see an unexpected result: The output follows the input:

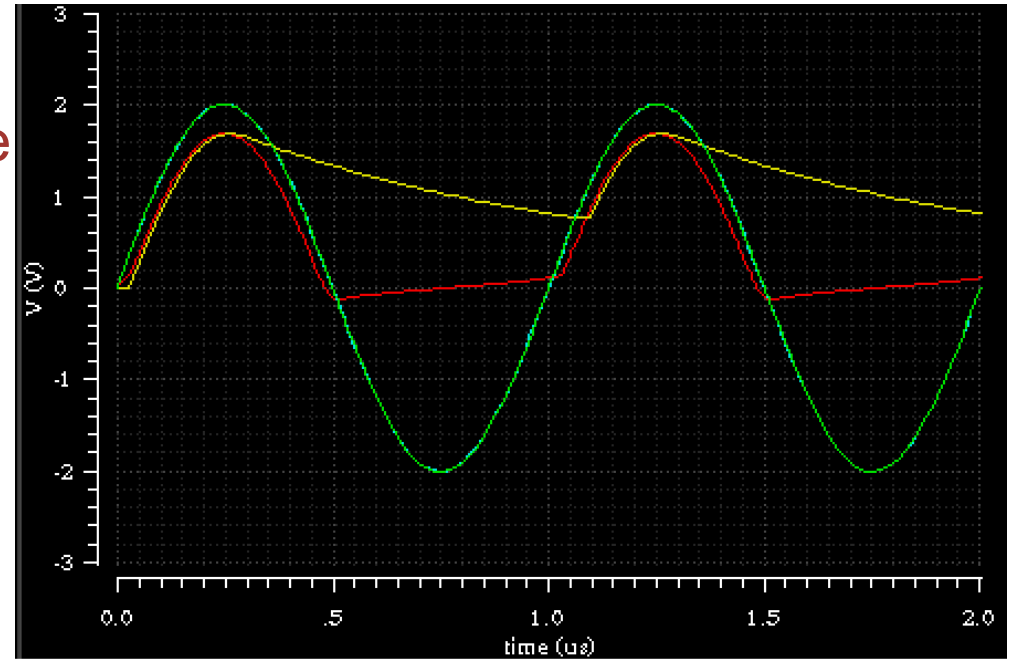


- How is that possible? -> This is due to the capacitance of the diode!!!! This can be proven by running at a much lower sine frequency...

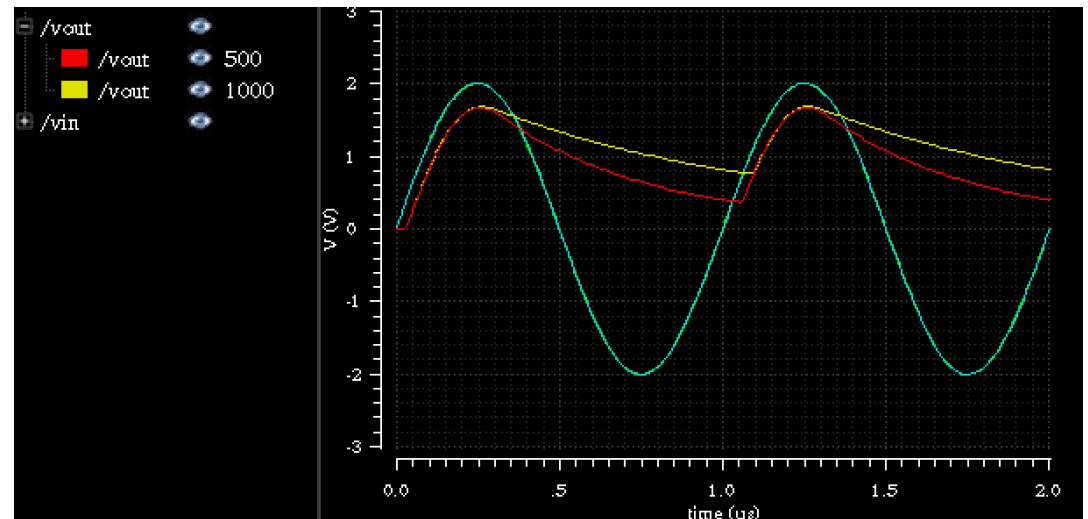


# Solution 4

- Adding 0/1nF (R=1k):
- The positive half wave charges the cap. This then holds the output positive in the negative half wave. It is discharged by R.



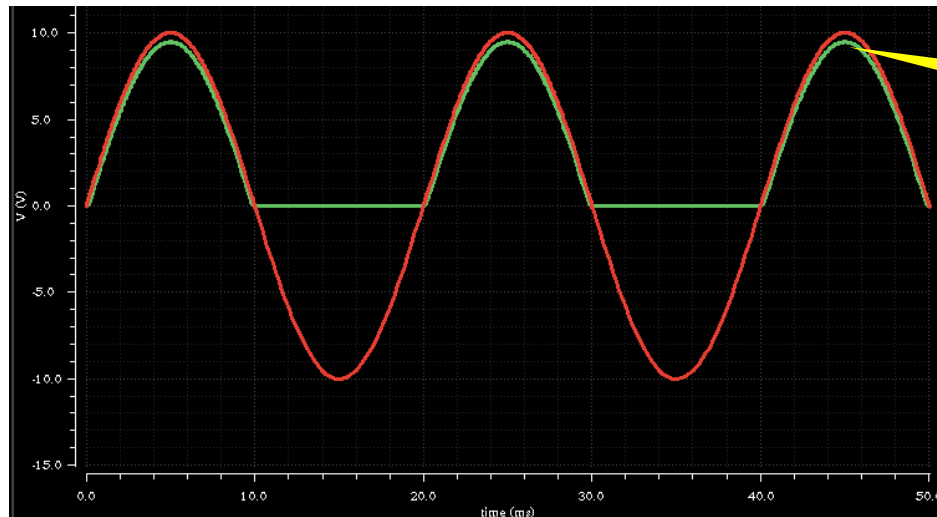
- Smaller R (C=1nF) discharges faster (R=500/1000):



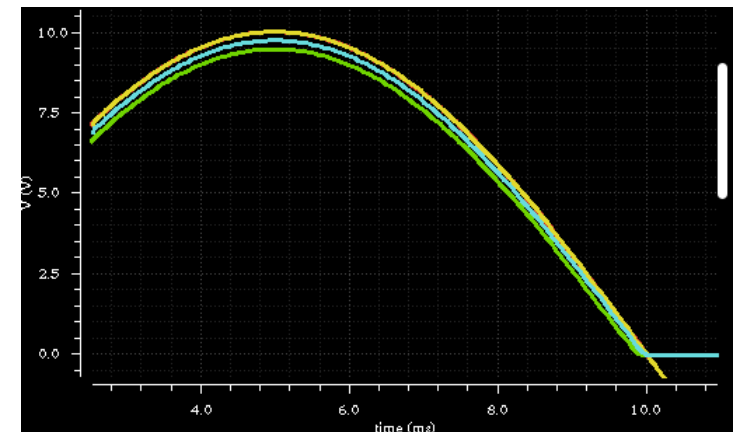


# Solution 4 (with 50 Hz)

- The voltage at the resistor rises to  $\sim 10V$ . This leads to a current of  $\sim 10V/1k \sim 10mA$ . This current leads to a (nonlinear) drop on the diode



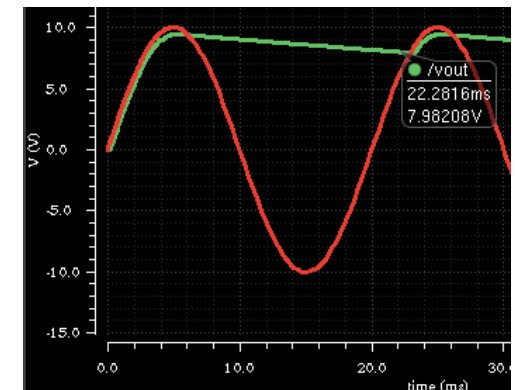
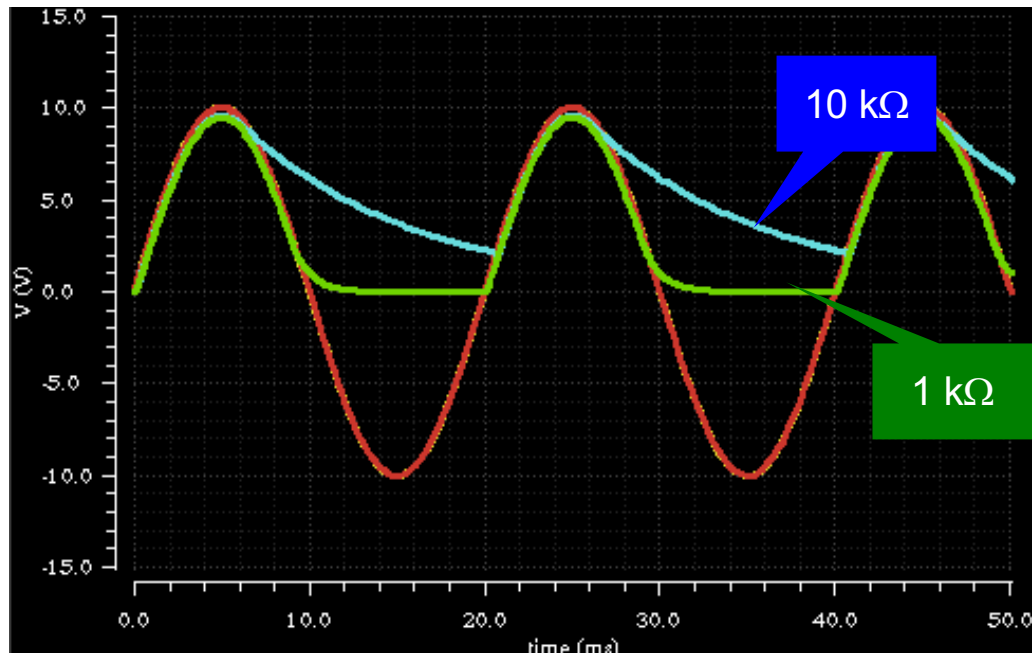
- At higher R, current is smaller and drop is smaller.





## Solution 4 (50 Hz)

- The cap is charged and keeps the voltage at the output high.
- It is then discharged by  $R_{load}$  with time constant  $\tau = R_{load}C$
- Discharge is slower for higher load resistors (and higher  $C$ ).



- Initial drop is  $dU/dT = I/C$ .  
This must be  $\sim 2V$  in  $20ms$  to reach  $8V$ .  
Therefore:  $C = I \, dT / dU = 10V / 1k\Omega \times 20ms / 2V = 100 \, \mu F$

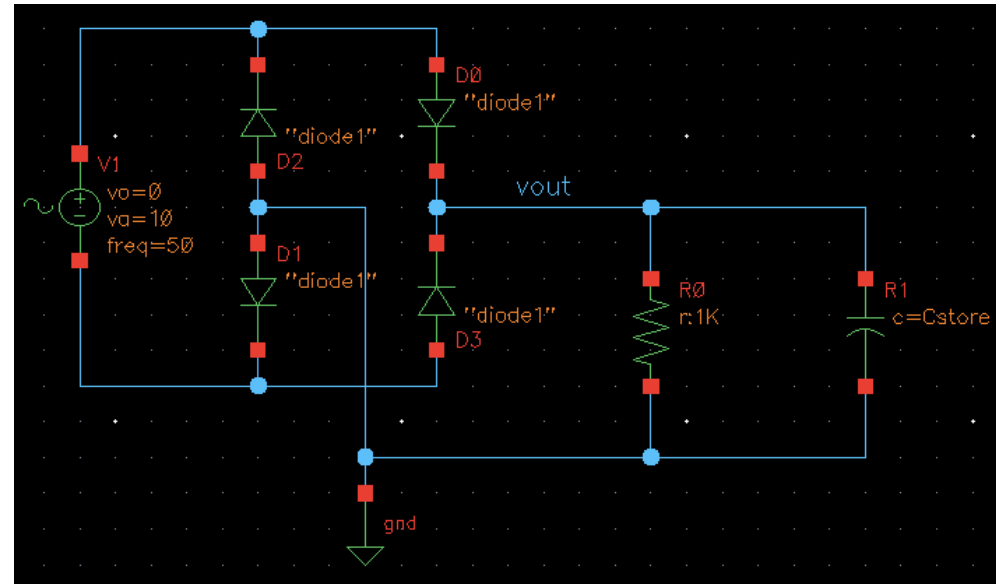
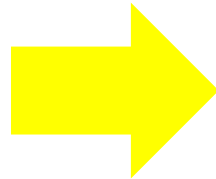
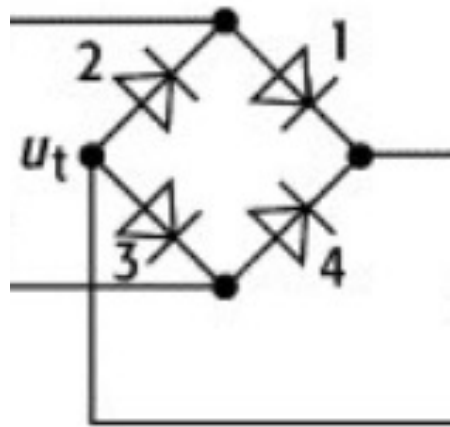




# 5: Full Wave Rectifier

- The full wave rectifier ('Graetz') uses 4 diodes to utilize the negative half-wave as well:

- make a Schematic

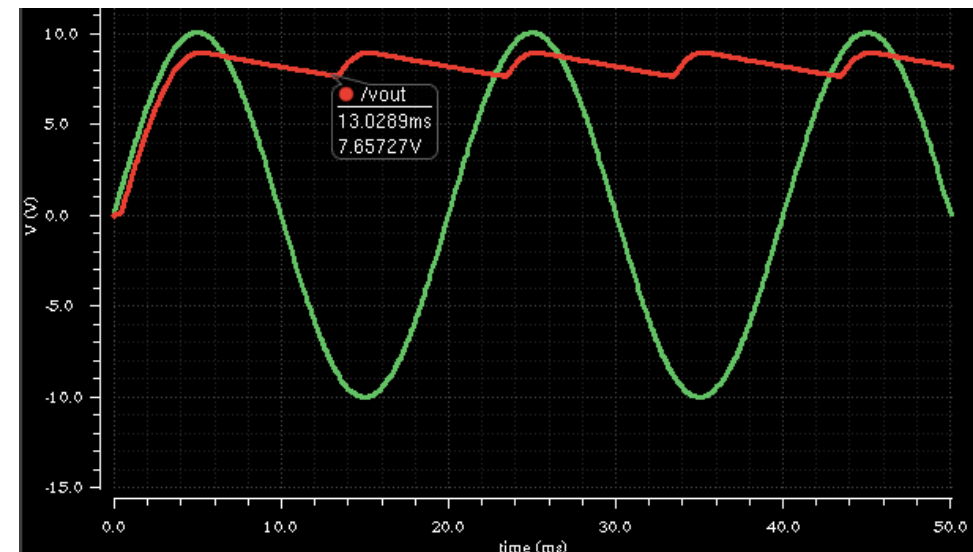
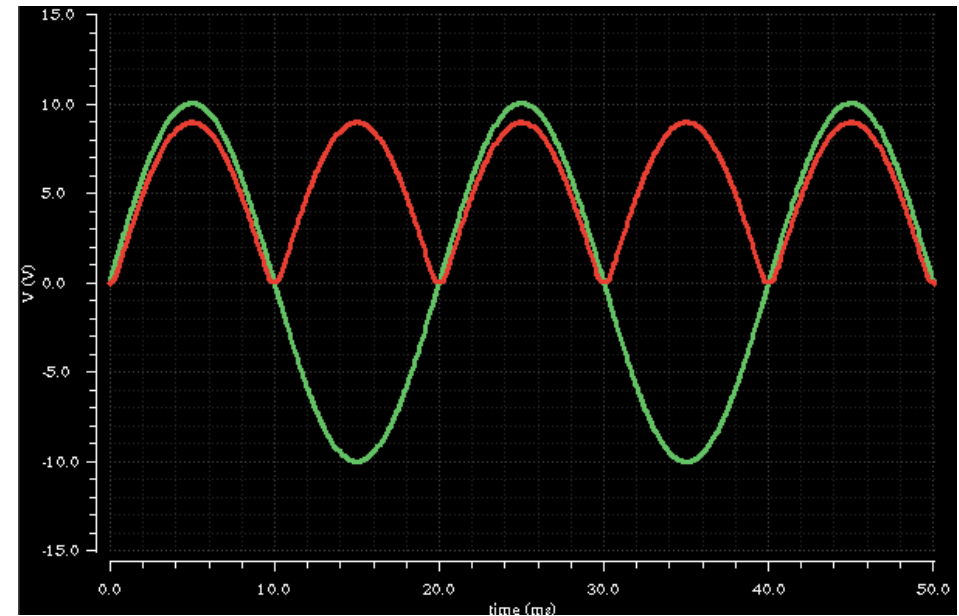


- How does  $V_{out}$  look like for  $C_{store} = 0$
- How does the circuit work?
- What is the peak amplitude? Why?
- What  $C_{load}$  do you need to guarantee  $V_{out} > 8V$ ? Calculate!



## Solution 5

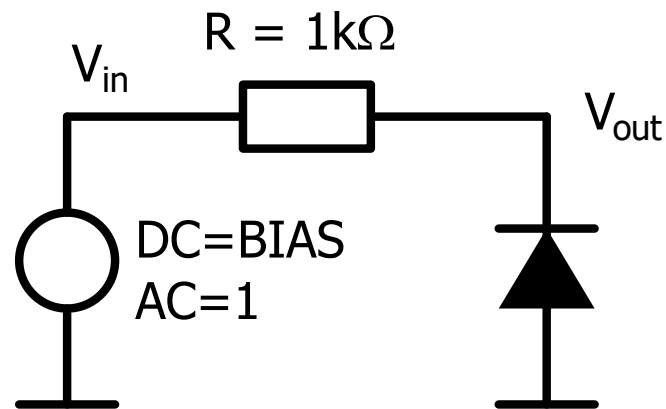
- The diodes provide a current path for both sine polarities.
- Two diodes in the path lead to twice the drop.
- Time is now half, so that half the cap is sufficient (50uF)





## Exercise 6: Operation Point

- A voltage dependent capacitance is part of the diode model.
- Implement the following circuit:



```
.MODEL diode1 d
+IS=1e-08 RS=0.05 N=1.5 EG=0.6
+XTI=0.05 BV=50 IBV=5e-08 CJO=1e-11
+VJ=0.7 M=0.5 FC=0.5 TT=1e-09
```

- Make an AC sweep from 1M to 1G or so for BIAS = 1V
  - What is the corner frequency?
- Change BIAS to 10V or 0.5V
  - Does the corner frequency change?
  - Is it changing in the right 'direction'?



## Solution 6

- Varying DC bias changes capacitance of the diode (higher reverse bias -> smaller capacitance)
- Therefore the corner frequency varies:

